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Code No.: 7121 M

VASAVI COLLEGE OF ENGINEERING (Autonomous), HYDERABAD
M.E. I Year (EEE) I-Semester (Make Up) Examinations, March-2016
(Power Systems & Power Electronics)

Power Semiconductor Devices and Circuits

Time: 3 hours

Max. Marks: 70

Note: Answer ALL questions in Part-A and any FIVE questions from Part-B

Part-A (10 X 2=20 Marks)

- Complete the following sentences.
 - A power MOSFET is a - polar device.
 - A power MOSFET is a - controlled device.
- Draw the "Safe Operating Areas (SOAs)" of IGBT, both with forward-bias and reverse-bias.
- Explain in one or two sentences the purpose of using a high value inductor in the step-down IGBT chopper.
- Complete the sentence. "In a step-down chopper using an IGBT, a diode and an inductor, the main purpose of the diode is"
- Give the two disadvantages of a three-phase square-wave inverter.
- Give the definition of "modulation index" for the PWM control of inverter.
- Complete the sentence. "A resonant tank in a resonant converter contains at least two main components, which are and"
- Complete the sentence. "The main function of resonant switch converter is to reduce the switching losses in the IGBTs by"
- Give in one sentence how the DC output voltage can be controlled in the Switched Mode Power Supply (SMPS).
- Complete the sentence. "The size of the power transformer in a Switched Mode Power Supply is reduced by operating the transformer at high"

Part B (5 X 10= 50 Marks)

- Give a neat sketch showing basic structure of a "Depletion Enhancement" MOSFET, and explain the operation of DE MOSFET in depletion mode only. (5)
 - Briefly explain the possibility of static latching up of IGBT. (5)
- A step-down chopper has a resistive load of 15 ohms and input voltage of 200 V. When the chopper remains ON, its voltage-drop is 2.5 V. The chopper frequency is 1000 Hz. For a duty-cycle of 50 %, calculate the average and RMS values of output voltage. (5)
 - Explain the principle of operation of a DC-to-DC converter circuit, where both step-up and step-down operations can be realized using only one chopper circuit. (5)
- For a three-phase bridge inverter, explain the operation of the inverter with 180° conduction mode with resistive load. (5)
 - For the inverter operation given in (a) above, draw the voltage waveforms of three phases and line. (5)

- 14 (a) Giving the basic circuit of a parallel-loaded resonant L- C converter, derive the expressions for resonant frequency, quality factor and voltage gain, and draw the plot of frequency response (voltage gain versus frequency ratio for increasing value of quality factor). (5)
- (b) Explain the principle of a full-bridge series resonant (load resonant / self-commutating) inverter with bidirectional switches with the help of a circuit diagram and waveforms of current and voltage. (5)
- 15 (a) Give the basic circuit diagram of a flyback converter operating in a continuous mode. Explain the function of each component in the circuit. (5)
- (b) For the flyback converter given in (a) above, give the waveforms of different voltages, currents, etc. Give two advantages and two disadvantages of the continuous mode. (5)
- 16 (a) Give comparison between Power MOSFET and IGBT in the form of a table. (4)
- (b) For a Gate Turn-Off Thyristor (GTO), give the circuit symbol, explain the two-transistor analogy, and discuss the basic structure showing anode-to-N base short-circuiting spots. (6)
- 17 (a) With the help of associated waveforms (carrier signal, reference signal and generated gate pulses), explain the principle of sinusoidal pulse-width modulation (PWM) using unidirectional triangular carrier wave as applied to voltage control of inverters. (6)
- (b) For the resonant-switch (quasi-resonant) converters, give various favourable features and the main drawbacks. (4)
